



QUALITY
SEMICONDUCTOR, INC.

High-Speed 3.3V CMOS 8-Bit Transparent Latch with Output Resistor and Bus Hold

QS74LCX2H573

FEATURES/BENEFITS

- 5V tolerant inputs and outputs
- 25Ω series resistor for low switching noise
- Bus Hold feature holds last active state during 3-state operation
- $10\mu A$ I_{CCQ} quiescent power supply current
- Hot insertable
- 2.0V-3.6V V_{CC} supply operation
- $\pm 12mA$ balanced output drive
- Power down high impedance inputs and outputs
- Meets or exceeds JEDEC 36 specifications
- C speed performance: $t_{PD} = 5.4ns$
- Input hysteresis for noise immunity
- Operating temperature range:
 $-40^{\circ}C$ to $85^{\circ}C$
- Latch-up performance exceeds 500mA
- Packages available:
 20-pin QSOP
 20-pin SOIC

DESCRIPTION

The LCX2H573 is an 8-bit buffered latch with three-state outputs that is ideal for driving high capacitance loads such as memory address and data buses. The QS74LCX2H573 with integrated output resistor is ideally suited for low noise environments where reduced output overshoot and undershoot are critical requirements. Bus Hold circuitry on the data inputs retains the last active state during 3-state operation, eliminating the need for external pull-up resistors. The 3.3V LCXPlus family features low power, low switching noise, and fast switching speeds for low power portable applications as well as high-end, advanced workstation applications. 5V tolerant inputs and outputs allow this LCXPlus product to be used in mixed 5V and 3.3V applications. To accommodate hot-plug or live insertion applications, this product is designed not to load an active bus when V_{CC} is removed.

Figure 1. Functional Block Diagram

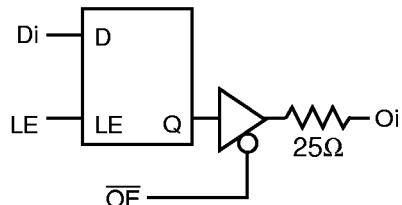


Figure 2. Pin Configurations
(All Pins Top View)

SOIC, QSOP

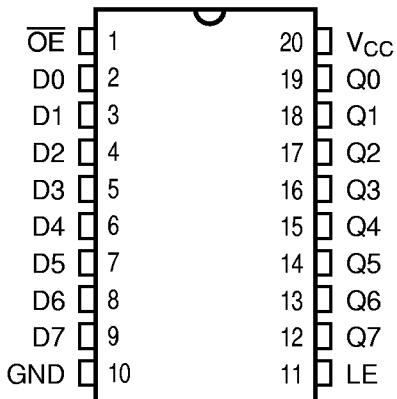


Table 1. Pin Description

Name	I/O	Description
Di	I	Data Inputs (Bus Hold Inputs)
Oi	O	Data Outputs
LE	I	Latch Enable
OE	I	Output Enable

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Table 2. Function Table

Inputs			Internal Q Value	Outputs O _i	Function
OE	LE	Di			
H	X	X	X	Z	Disable Outputs
L	L	X	L	L	Enable Outputs
L	L	X	H	H	
X	H	L	L	L	Pass Input Data
X	H	H	H	H	
L	L	X	Q	Q	Hold Prior Data

Table 3. Capacitance

Symbol	Pins	Typ	Unit	Conditions
C _{IN}	Input Capacitance	7.0	pF	V _{IN} = 0V, V _{OUT} = 0V, f = 1MHz
C _{I/O}	I/O Capacitance	8.0	pF	V _{IN} = 0V, V _{OUT} = 0V, f = 1MHz
C _{PD}	Power Dissipation Capacitance	20	pF	V _{CC} = 3.3V, V _{IN} = 0V, or V _{CC} f = 10MHz

Note: Capacitance is characterized, but not production tested.

Table 4. Absolute Maximum Ratings

Supply Voltage to Ground	-0.5V to 7.0V
DC Output Voltage V _{OUT}	
Outputs HIGH-Z.....	-0.5V to 7.0V
Outputs Active	-0.5V to V _{CC} + 0.5V
DC Input Voltage V _{IN}	-0.5V to 7.0V
DC Input Diode Current with V _{IN} < 0	-50mA
DC Output Diode Current	
V _O < 0	-50mA
V _O > V _{CC}	50mA
DC Output Source/Sink Current (I _{OH} /I _{OL})	±50mA
DC Supply Current per Supply Pin	±100mA
DC Ground Current per Ground Pin	±100mA
T _{STG} Storage Temperature	-65° to 150°C

Note: Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to QSI devices that result in functional or reliability type failures.

Table 5. Recommended Operating Conditions

Symbol	Parameter		Min	Max	Unit
V _{CC}	Supply Voltage, Operating		2.0	3.6	V
	Supply Voltage, Data Retention Only		1.5	3.6	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage in Active State		0	V _{CC}	V
V _{OUT}	Output Voltage in "OFF" State		0	5.5	V
I _{OH} /I _{OL}	Output Current	V _{CC} = 3.0 – 3.6V	—	±12	mA
		V _{CC} = 2.7V	—	±6	
Δt/Δv	Input Transition Slew Rate		—	10	ns/V
T _A	Operating Free Air Temperature		-40	85	°C

Table 6. DC Electrical Characteristics Over Operating RangeIndustrial Temperature Range, $T_A = -40^\circ\text{C}$ to 85°C .

Symbol	Parameter	Test Conditions ⁽¹⁾	Min	Typ ⁽²⁾	Max	Unit
V_{IH}	Input HIGH Voltage	Logic HIGH for All Inputs	2.0	—	—	V
V_{IL}	Input LOW Voltage	Logic LOW for All Inputs	—	—	0.8	V
V_{OH}	Output HIGH Voltage	$V_{CC} = 2.7\text{V}$, $I_{OH} = -100\mu\text{A}$ $V_{CC} = 3.0\text{V}$, $I_{OH} = -12\text{mA}$ $V_{CC} = 3.0\text{V}$, $I_{OH} = -18\text{mA}$	$V_{CC} = 0.2$ 2.4 2.2	—	—	V
V_{OL}	Output LOW Voltage	$V_{CC} = 2.7\text{V}$, $I_{OL} = 100\mu\text{A}$ $V_{CC} = 3.0\text{V}$, $I_{OL} = 12\text{mA}$ $V_{CC} = 3.0\text{V}$, $I_{OL} = 18\text{mA}$	— — —	— — —	0.2 0.55 0.8	V
R_{OUT}	Output Resistance	$V_{CC} = 3.0\text{V}$, $I_{OL} = 12\text{mA}$	—	28	—	Ω
ΔV_T	Input Hysteresis ⁽³⁾	$V_{TLH} - V_{THL}$ for All Inputs	—	150	—	mV
$ I_{OZ} $	Off-State Output Current (Hi-Z)	$V_{CC} = 3.6\text{V}$, $V_O = 0\text{V}$, $V_O = 5.5\text{V}$	—	—	1.0	μA
I_{OS}	Short Circuit Current ^(3,4)	$V_{CC} = 3.6\text{V}$, $V_{OUT} = \text{GND}$	-60	—	-200	mA
I_{OR}	Current Drive ⁽³⁾	$V_{CC} = 3.6\text{V}$, $V_{OUT} = 2.0\text{V}$	40	—	—	mA
V_{IK}	Input Clamp Voltage	$V_{CC} = 2.7\text{V}$, $I_{IN} = -18\text{mA}$	—	-0.7	-1.2	V
I_I	Input Leakage Current	$V_I = 0\text{V}$, $V_I = 5.5\text{V}$, $V_{CC} = 3.6\text{V}$	—	—	± 1.0	μA
$ I_{BH} $	Input Current Input HIGH or LOW Bus Hold Inputs ^(3,5)	$V_{CC} = 3.6\text{V}$, $V_{IN} = 0\text{V}$ or $V_{IN} = V_{CC}$	—	—	50	μA
		$V_{CC} = 3.6\text{V}$, $0.8 < V_{IN} < 2.0\text{V}$	—	—	500 ⁽⁶⁾	μA
I_{BHH}	Bus Hold Sustaining Current Bus Hold Inputs	$V_{CC} = 3.0\text{V}$	$V_{IN} = 2.0\text{V}$	-75	—	—
I_{BHL}			$V_{IN} = 0.8\text{V}$	75	—	—
I_{OFF}	Power Off Leakage	$V_{CC} = 0\text{V}$, V_I or $V_O = 5.5\text{V}$	—	—	10	μA

Notes:

- For conditions shown as Min. or Max. use appropriate value specified under Recommended Operating Conditions for the applicable device type.
- Typical values are at $V_{CC} = 3.3\text{V}$ and $T_A = 25^\circ\text{C}$.
- These parameters are guaranteed by characterization, but not production tested.
- Not more than one output should be tested at one time. Duration of test should not exceed one second.
- Pins with Bus Hold are identified in the Pin Description.
- An external driver must provide at least $|I_{BH}|$ during transition to guarantee that the Bus Hold input will change state.

Table 7. Power Supply Characteristics

Symbol	Parameter	Test Conditions ⁽¹⁾		Typ ⁽²⁾	Max	Unit
I _{CC}	Quiescent Power Supply Current	V _{CC} = 3.6V, Freq = 0 V _{IN} = GND or V _{CC}		0.1	10	µA
ΔI _{CC}	Supply Current per Input @ TTL HIGH ⁽³⁾	V _{CC} = 3.6V	Control Inputs	2.0	30	µA
		V _{IN} = V _{CC} -0.6V, Freq = 0	Bus Hold Inputs	—	500	µA
I _{CCD}	Supply Current per Input per MHz ⁽⁴⁾	V _{CC} = 3.6V, Outputs Open One Bit Toggling @ 50% Duty Cycle OE = GND		50	75	µA/MHz
I _C	Total Power Supply Current ⁽⁶⁾	V _{CC} = 3.6V, Outputs Open One Bit Toggling @ 50% Duty Cycle OE = GND, f = 10MHz	V _{IN} = V _{CC} -0.6V V _{IN} = GND	0.5 ⁽⁵⁾	1.0 ⁽⁵⁾	mA
		V _{CC} = 3.6V, Outputs Open Eight Bits Toggling @ 50% Duty Cycle OE = GND, f = 2.5MHz	V _{IN} = V _{CC} -0.6V V _{IN} = GND	1.0 ⁽⁵⁾	3.5 ⁽⁵⁾	mA

Notes:

- For conditions shown as Min. or Max., use the appropriate values specified under Recommended Operating Conditions for applicable device type.
- Typical values are at V_{CC} = 3.3V, 25°C ambient.
- Per TTL driven input. All other inputs at V_{CC} or GND.
- This parameter is not directly testable, but is derived for use in total power supply calculations.
- Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed by design but not tested.
- I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}.
I_C = I_{CCQ} + ΔI_{CC} D_H N_T + I_{CCD} f N_O.
I_{CCQ} = Quiescent Current (I_{CCL}, I_{CCH}, and I_{CCZ}).
ΔI_{CC} = Power Supply Current for a TTL-High Input (V_{IN} = V_{CC}-0.6V).
D_H = Duty Cycle for TTL High Inputs.
N_T = Number of TTL High Inputs.
I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL).
f = Average Switching Frequency per Output.
N_O = Number of Outputs Switching.

Table 8. Dynamic Switching Characteristics⁽¹⁾

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C		Units
				Typical		
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	C _L = 30pF, V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8		V
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	C _L = 30pF, V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8		V

Note:

- Characterized but not production tested.

Table 9. Switching Characteristics Over Operating RangeIndustrial Temperature Range, $T_A = -40^\circ\text{C}$ to 85°C . $C_{\text{LOAD}} = 30\text{pF}$, $R_{\text{LOAD}} = 500\Omega$ unless otherwise noted.

Symbol	Description ⁽¹⁾	2H573				2H573C		Unit	
		$V_{\text{CC}} = 3.3 \pm 0.3\text{V}$		$V_{\text{CC}} = 2.7\text{V}^{(2)}$		$V_{\text{CC}} = 3.3\text{V} \pm 0.3\text{V}$			
		Min	Max	Min	Max	Min	Max		
t_{PHL}	Propagation Delay Di to Oi	1.5	8.0	1.5	9.0	1.5	5.4	ns	
t_{PLH}	Propagation Delay LE to Oi	1.5	8.5	1.5	9.5	2.0	5.5	ns	
t_{PZH}	Output Enable Time $\overline{\text{OE}}$ to Oi	1.5	8.5	1.5	9.5	1.5	6.2	ns	
t_{PHZ}	Output Disable Time $\overline{\text{OE}}$ to Oi ⁽²⁾	1.5	6.5	1.5	7.0	1.5	6.0	ns	
t_s	Data Setup Time Di to LE HIGH to LOW	2.5	—	2.5	—	2.0	—	ns	
t_h	Data Hold Time Di to LE HIGH to LOW	1.5	—	1.5	—	1.5	—	ns	
t_w	LE Pulse Width HIGH or LOW ⁽²⁾	3.3	—	3.3	—	3.3	—	ns	
$t_{\text{SK(O)}}$	Output Skew ⁽³⁾	—	0.5	—	—	—	0.5	ns	

Notes:

1. Minimums guaranteed but not production tested. See test circuit and waveforms.
2. Guaranteed by characterization.
3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by characterization, but not production tested.

TEST CIRCUIT AND WAVEFORMS

Figure 3. Test Circuit

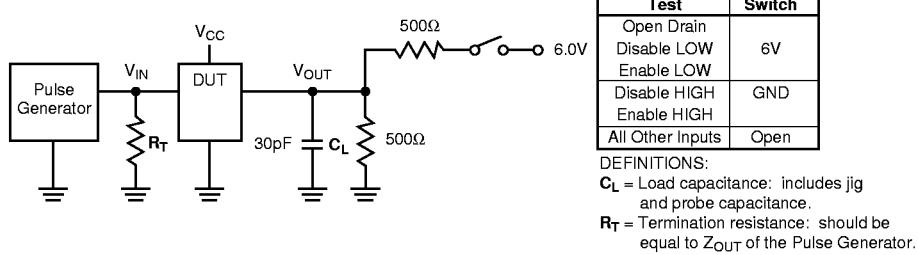


Figure 4. Setup, Hold, and Release Timing

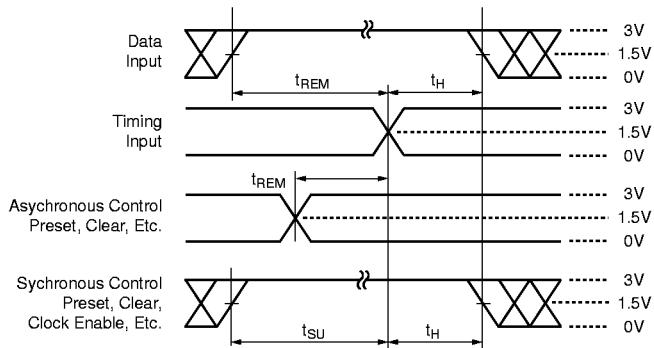


Figure 6. Pulse Width

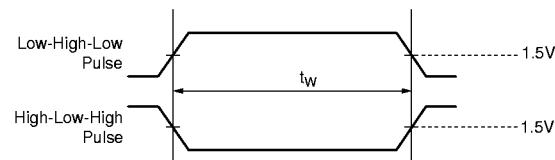


Figure 5. Enable and Disable Timing

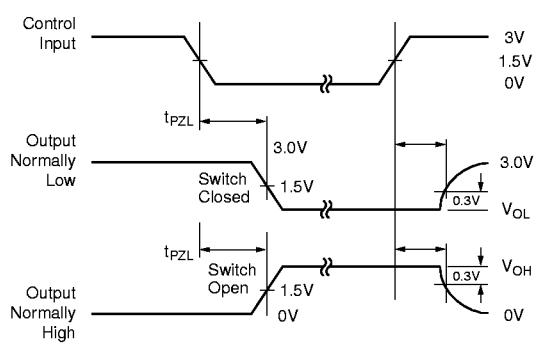
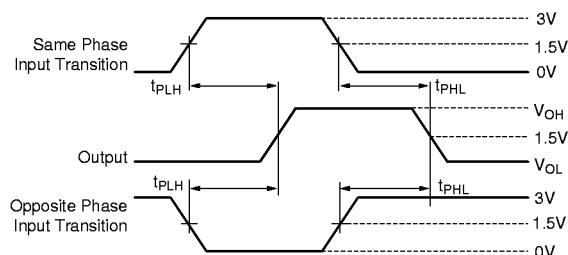


Figure 7. Propagation Delay

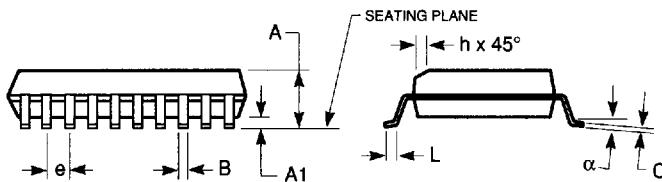
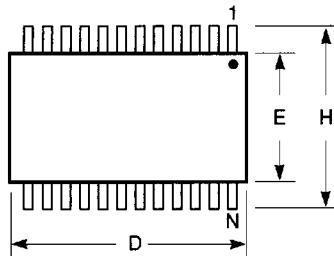


Notes:

1. Input Control Enable = LOW and Input Control Disable = HIGH.
2. Pulse Generator for All Pulses: Rate $\leq 1.0\text{MHz}$;
 $Z_{OUT} \leq 50\Omega$; $t_F, t_R \leq 2.5\text{ns}$.

300-MIL SOIC - Package Code SO

Plastic Small Outline Gull-Wing



Notes:

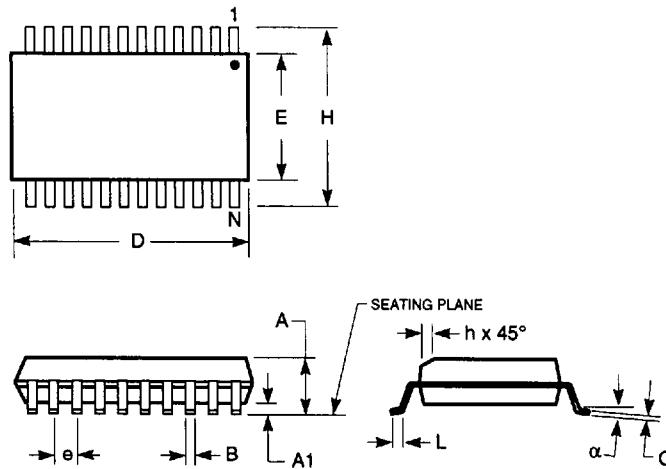
1. Refer to applicable symbol list.
2. All dimensions are in inches.
3. N is the number of lead positions.
4. Dimensions D and E are to be measured at maximum material condition but do not include mold flash. Allowable mold flash is 0.006in. per side.
5. Lead coplanarity is 0.004in. maximum.

JEDEC#	MS-013AA		MS-013AC		MS-013AD		MS-013AE	
DWG#	PS16A		PS20A		PS24A		PS28A	
Symbol	Min	Max	Min	Max	Min	Max	Min	Max
A	0.096	0.104	0.096	0.104	0.096	0.104	0.096	0.104
A1	0.005	0.011	0.005	0.011	0.005	0.011	0.005	0.011
B	0.014	0.019	0.014	0.019	0.014	0.019	0.014	0.019
C	0.009	0.012	0.009	0.012	0.009	0.012	0.009	0.012
D	0.402	0.412	0.500	0.510	0.602	0.612	0.701	0.711
E	0.292	0.299	0.292	0.299	0.292	0.299	0.292	0.299
e	0.044	0.056	0.044	0.056	0.044	0.056	0.044	0.056
H	0.396	0.416	0.396	0.416	0.396	0.416	0.396	0.416
h	0.010	0.016	0.010	0.016	0.010	0.016	0.010	0.016
L	0.020	0.040	0.020	0.040	0.020	0.040	0.020	0.040
N	16		20		24		28	
α	0°	8°	0°	8°	0°	8°	0°	8°

■ 7466803 0003749 900 ■

150-MIL SOIC - Package Code S1

Plastic Small Outline Gull-Wing



JEDEC#		MS-012AB			MS-012AC		
DWG#		PS-14B			PS-16B		
Symbol		Min	Nom	Max	Min	Nom	Max
A		0.060	0.064	0.068	0.060	0.064	0.068
A1		0.004	0.006	0.008	0.004	0.006	0.008
B		0.014	0.016	0.019	0.014	0.016	0.019
C		0.0075	0.008	0.0098	0.0075	0.008	0.0098
D		0.337	0.341	0.346	0.386	0.390	0.394
E		0.150	0.154	0.157	0.150	0.154	0.157
e		0.050 BSC			0.050 BSC		
H		0.230	0.236	0.244	0.230	0.236	0.244
h		0.010	0.013	0.016	0.010	0.013	0.016
L		0.016	0.025	0.035	0.016	0.025	0.035
N		14			16		
α		0°	5°	8°	0°	5°	8°

Notes:

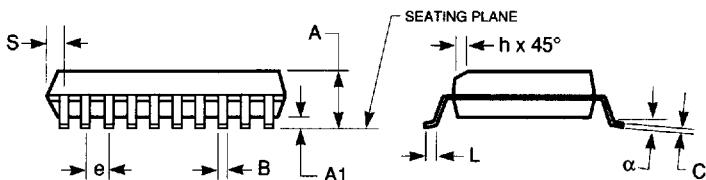
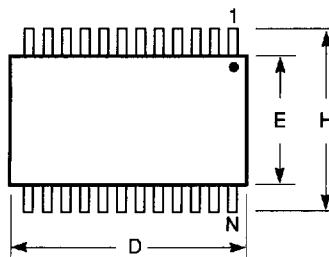
- Refer to applicable symbol list.
- All dimensions are in inches.
- N is the number of lead positions.
- Dimensions D and E are to be measured at maximum material condition but do not include mold flash. Allowable mold flash is 0.006 in. per side.
- Lead coplanarity is 0.004 in. maximum.

7466803 0003750 622

150-MIL QSOP - Package Code Q

Quarter-Size Outline Package

Plastic Small Outline Gull-Wing



JEDEC#	MO-137AB			MO-137AD			MO-137AE			MO-137AF		
DWG#	PSS-16A			PSS-20A			PSS-24A			PSS-28A		
Symbol	Min	Nom	Max									
A	0.060	0.064	0.068	0.060	0.064	0.068	0.060	0.064	0.068	0.060	0.064	0.068
A1	0.004	0.006	0.008	0.004	0.006	0.008	0.004	0.006	0.008	0.004	0.006	0.008
B	0.009	0.010	0.012	0.009	0.010	0.012	0.009	0.010	0.012	0.009	0.010	0.012
C	0.007	0.008	0.010	0.007	0.008	0.010	0.007	0.008	0.010	0.007	0.008	0.010
D	0.189	0.193	0.197	0.337	0.341	0.344	0.337	0.341	0.344	0.386	0.390	0.394
E	0.150	0.154	0.157	0.150	0.154	0.157	0.150	0.154	0.157	0.150	0.154	0.157
e	0.025 BSC											
H	0.230	0.236	0.244	0.230	0.236	0.244	0.230	0.236	0.244	0.230	0.236	0.244
h	0.010	0.013	0.016	0.010	0.013	0.016	0.010	0.013	0.016	0.010	0.013	0.016
L	0.016	0.025	0.035	0.016	0.025	0.035	0.016	0.025	0.035	0.016	0.025	0.035
N	16			20			24			28		
α	0°	5°	8°	0°	5°	8°	0°	5°	8°	0°	5°	8°
S	0.006	0.009	0.010	0.056	0.058	0.060	0.031	0.033	0.035	0.031	0.033	0.035

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